

GS5M

5.0AMPS . GLASS PASSIVATED RECTIFIERS

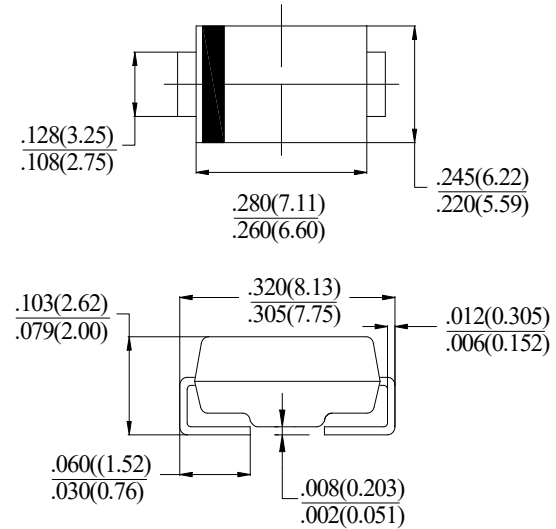
SMC (DO-214AB)

FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed:
260°C/10 seconds at terminals.
- . For surface mounted application.
- . Easy pick and place.

MECHANICAL DATA

- . Terminal: Solder plated
- . Case: Molded with UL-94 Class V-0 recognized
Flame Retardant Epoxy (free halogen)
- . Polarity: color band denotes cathode



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	SYM BOL	GS5M	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS Voltage	V_{RMS}	700	V
Maximum DC blocking Voltage	V_{DC}	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	5.0	A
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load (JEDEC method)	I_{FSM}	120.0	A
Maximum Forward Voltage at 5.0 A DC	V_F	1.1	V
Maximum DC Reverse Current @ $T_J=25^{\circ}C$ at rated DC blocking voltage @ $T_J=125^{\circ}C$	I_R	5.0 200.0	μA
I^2t Rating for Fusing ($t < 8.3ms$)	I^2t	59.7	A ² Sec
Typical Junction Capacitance (Note1)	C_J	35	pF
Typical Thermal Resistance (Note 2)	$R_{(JA)}$	50	$^{\circ}C /W$
	$R_{(JC)}$	12	
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$
Operation Junction Temperature	T_J	-55 to +150	$^{\circ}C$

Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
2. Measured on P.C.Board with 0.6×0.6”(15.0×15.0mm)Copper Pad Areas.

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

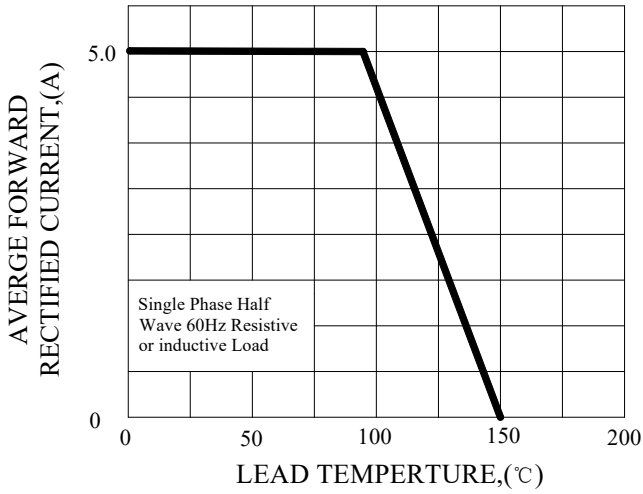


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

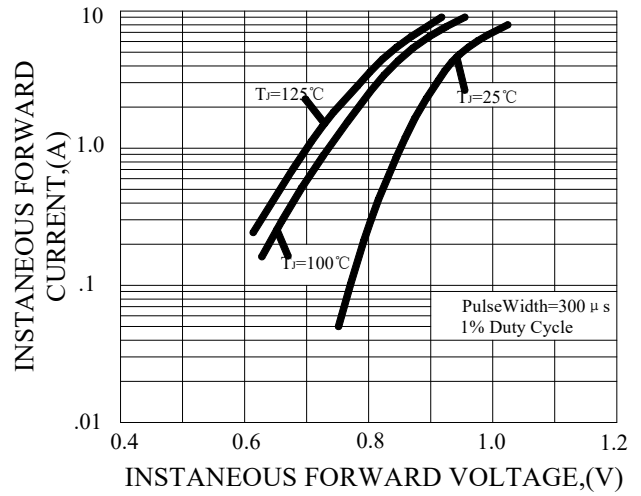


FIG.3-MAXIMUN NON-REPETITIVE FORWARD SURGE CURRENT

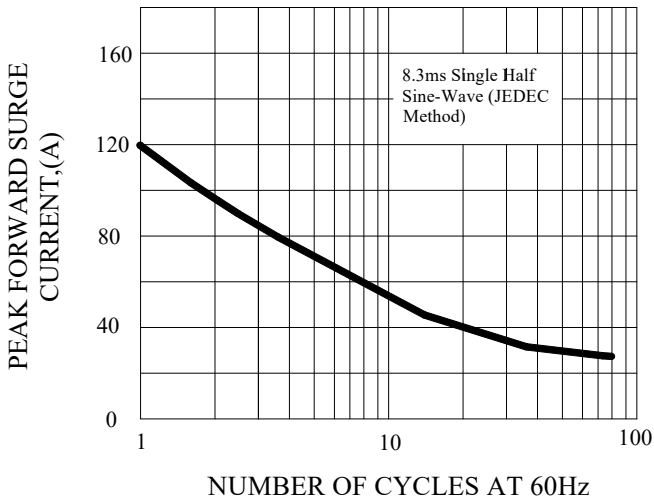


FIG.4-TYPICAL REVERSE CHARACTERISTICS

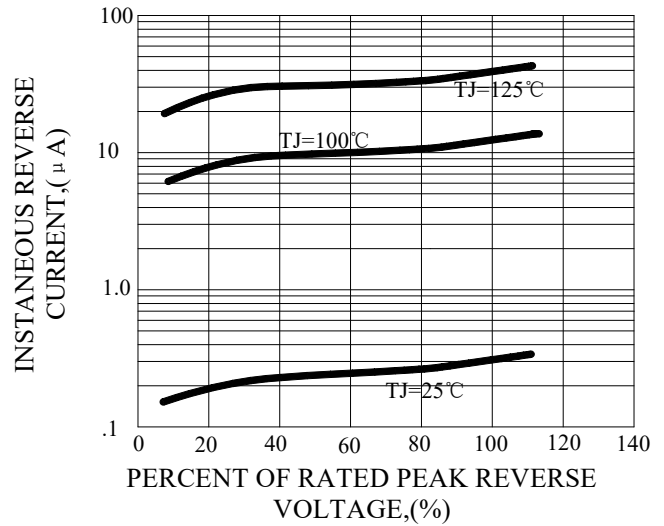
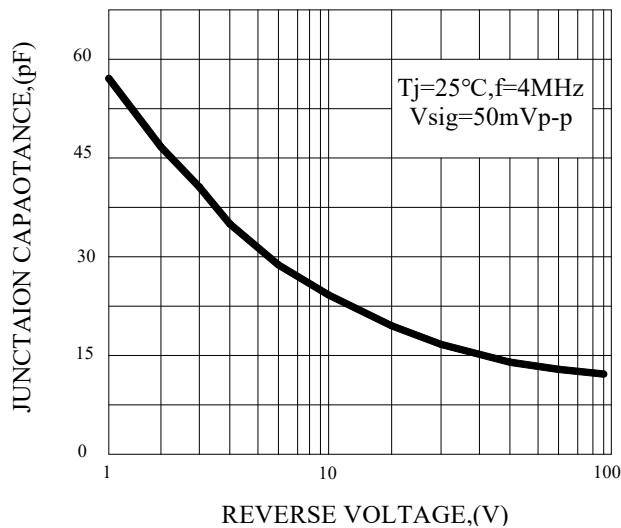
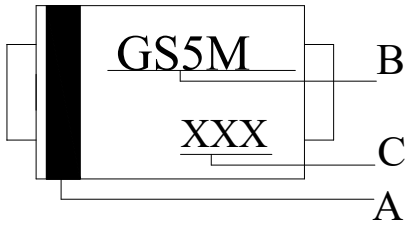


FIG.5-TYPICAL JUNCTION CAPACITANCE



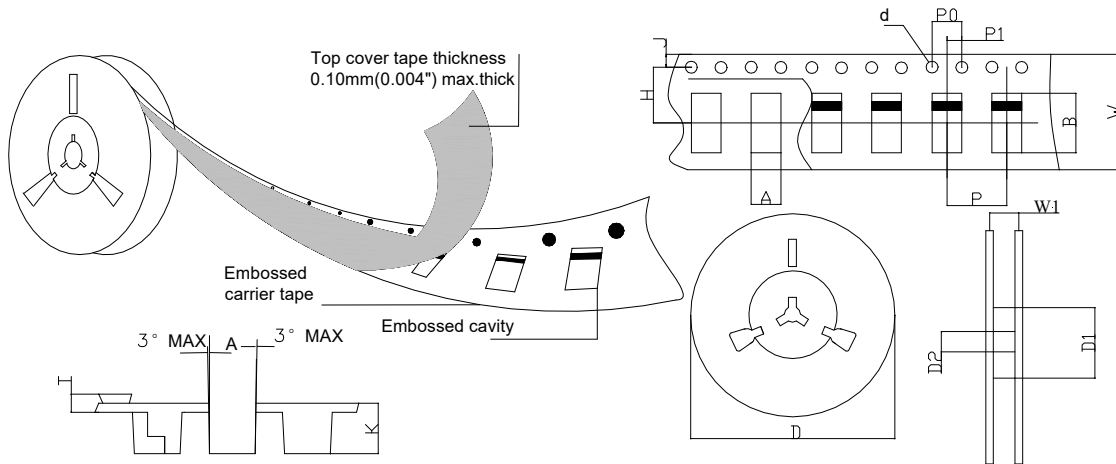
Marking and packaging illustration

1、Marking



SYMBOL	Explanation
A	Color Band Denotes Cathode
B	Product Name
C	Date Code

2、Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	SMC (DO-214AB)	ITEM	SYM BOL	SMC (DO-214AB)
Carrier width	A	6.15(0.242)Max	Carrier depth	K	2.54(0.100)Typ
Carrier length	B	8.41(0.331)Max	Punch hole pitch	P	8.00(0.315)Typ
Sprocket hole	d	ø1.55(0.061)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	330.0(13.0)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	74.0(2.913)Min	Overall tape thickness	T	0.25(0.010)Typ
Feed hole diameter	D2	13.0(0.512)Typ	Tape width	W	16.0(0.430)Typ
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	16.5(0.650)Min
Punch hole position	H	7.50(0.295)Typ			

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Diodes - General Purpose, Power, Switching category](#):

Click to view products by [Pingwei manufacturer](#):

Other Similar products are found below :

[MMBD3004S-13-F](#) [1N3611](#) [NTE156A](#) [NTE6244](#) [1SS400CST2RA](#) [SDAA13](#) [SHN2D02FUTW1T1G](#) [1N4449](#) [1N456A](#) [1N914BTR](#)
[D291S45T](#) [BAS 16-02L E6327](#) [BAS 16-02V H6327](#) [BAS 21U E6327](#) [BAS 28 E6327](#) [BAW56DWQ-7-F](#) [BAW56M3T5G](#) [BAW75-TAP](#)
[MM230L-CAA](#) [IDW40E65D1](#) [JAN1N3600](#) [JAN1N4454UR-1](#) [SMMSD4148T3G](#) [BYW95B/A52A](#) [NSVDAN222T1G](#) [CDSZC01100-HF](#)
[BAV70HDW-7](#) [BAS28-7](#) [JANTX1N6640](#) [BAW56HDW-13](#) [BAS28 TR](#) [VS-HFA04SD60STR-M3](#) [1SS388-TP](#) [BAV99TQ-13-F](#)
[BAV99HDW-13](#) [1N4004](#) [MMDB30-E28X](#) [LS4148](#) [IDV15E65D2](#) [W0503RH200S0L](#) [W0503SH200S0L](#) [M0268SJ200NLF](#)
[M0268RJ200NLF](#) [S3MBF](#) [US1J](#) [DAN217U-TP](#) [SHV-06JNS-Q](#) [IDW30C65D1](#) [IDW80C65D1](#) [VS-HFA30TA60CSR-M3](#)